

*Librería*

# *Bonilla y Asociados*

*desde 1950*



**Título:**

**Autor:**

**Precio:** \$3438.00

**Editorial:**

**Año:** 1996

**Tema:**

**Edición:**

**Sinopsis**

**ISBN:** 9780132543354

A unified presentation of the analysis and design of microwave transistor amplifiers (and oscillators) – using scattering parameters techniques. KEY FEATURES: Presents material on: transmission-lines concepts; power waves and generalized scattering parameters; measurements of scattering parameters; bipolar and field-effect transistors; power gain expressions; constant VSWR circles; gain, noise, and VSWR design trade offs; broadband amplifiers, high-power amplifiers; oscillator